

HEX INVERTERS WITH OPEN COLLECTOR OUTPUTS**DESCRIPTION**

The M74LS05P is a semiconductor integrated circuit containing 6 open collector output inverter circuits.

FEATURES

- Usable in AND-Tie connection.
- High breakdown input voltage ($V_I \geq 15V$)
- Low power dissipation ($P_d = 12mW$ typical)
- High speed ($t_{pd} = 10ns$ typical)
- Wide operating temperature range ($T_a = -20 \sim +75^\circ C$)

APPLICATION

General purpose, for use in industrial and consumer equipment.

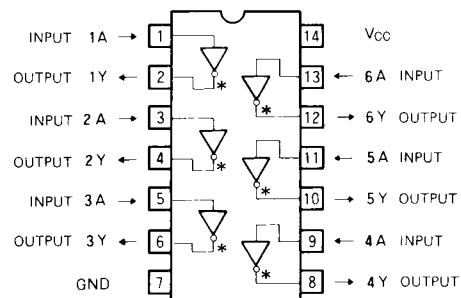
FUNCTIONAL DESCRIPTION

With the use of Schottky barrier diodes for the inputs and open-collector outputs, the high-level output impedance can be selected freely by use of an external load resistor. This permits wire-AND connection, which has been impossible with conventional gates.

When input A is high, output Y is low, and when A is low, Y is high.

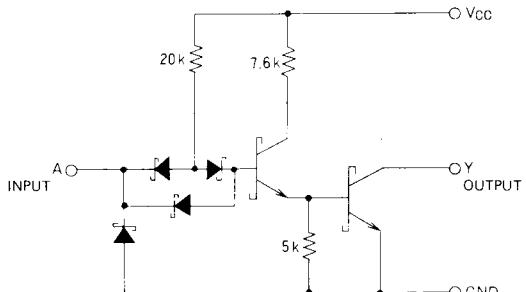
FUNCTION TABLE

A	Y
L	H
H	L

PIN CONFIGURATION (TOP VIEW)

* : OPEN COLLECTOR OUTPUT

Outline 14P4

CIRCUIT SCHEMATIC (EACH INVERTER)

UNIT : Ω

ABSOLUTE MAXIMUM RATINGS ($T_a = -20 \sim +75^\circ C$, unless otherwise noted)

Symbol	Parameter	Conditions	Limits	Unit
V _{CC}	Supply voltage		-0.5 ~ +7	V
V _I	Input voltage		-0.5 ~ +15	V
V _O	Output voltage	High-level state	-0.5 ~ +7	V
T _{opr}	Operating free-air ambient temperature range		-20 ~ +75	°C
T _{stg}	Storage temperature range		-65 ~ +150	°C

HEX INVERTERS WITH OPEN COLLECTOR OUTPUTS

RECOMMENDED OPERATING CONDITIONS ($T_a = -20 \sim +75^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Limits			Unit
		Min	Typ	Max	
V_{CC}	Supply voltage	4.75	5	5.25	V
I_{OH}	High-level output current	0		100	μA
I_{OL}	$V_O = 5.5\text{V}$	0		4	mA
	$V_{OL} \leq 0.4\text{V}$	0		8	mA

ELECTRICAL CHARACTERISTICS ($T_a = -20 \sim +75^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ*	Max	
V_{IH}	High-level input voltage		2			V
V_{IL}	Low-level input voltage				0.8	V
V_{IC}	Input clamp voltage	$V_{CC} = 4.75\text{V}$, $I_{IC} = -18\text{mA}$			-1.5	V
I_{OH}	High-level output current	$V_{CC} = 4.75\text{V}$, $V_I = 0.8\text{V}$, $V_O = 5.5\text{V}$			100	μA
V_{OL}	Low-level output voltage	$V_{CC} = 4.75\text{V}$	$I_{OL} = 4\text{mA}$	0.25	0.4	V
		$V_I = 2\text{V}$	$I_{OL} = 8\text{mA}$	0.35	0.5	V
I_{IH}	High-level input current	$V_{CC} = 5.25\text{V}$, $V_I = 2.7\text{V}$			20	μA
		$V_{CC} = 5.25\text{V}$, $V_I = 10\text{V}$			0.1	mA
I_{IL}	Low-level input current	$V_{CC} = 5.25\text{V}$, $V_I = 0.4\text{V}$			-0.4	mA
I_{COH}	Supply current, all outputs high	$V_{CC} = 5.25\text{V}$, $V_I = 0\text{V}$			1.2	mA
I_{CCL}	Supply current, all outputs low	$V_{CC} = 5.25\text{V}$, $V_I = \text{open}$			3.6	mA

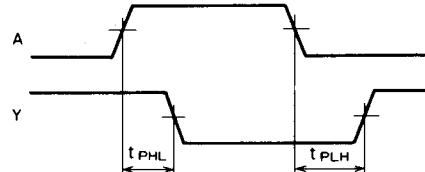
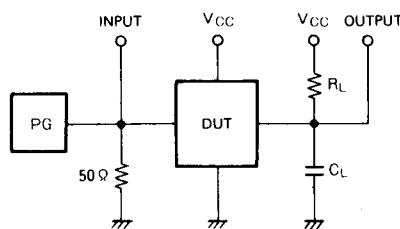
* : All typical values are at $V_{CC} = 5\text{V}$, $T_a = 25^\circ\text{C}$.

SWITCHING CHARACTERISTICS ($V_{CC} = 5\text{V}$, $T_a = 25^\circ\text{C}$, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
t_{PLH}	Low-to-high-level output propagation time	$R_L = 2\text{k}\Omega$		10	32	ns
t_{PHL}	High-to-low-level output propagation time	$C_L = 15\text{pF}$ (Note 1)		10	28	ns

Note 1: Measurement circuit

TIMING DIAGRAM (Reference level = 1.3V)



- (1) The pulse generator (PG) has the following characteristics:
 $\text{PRR} = 1\text{MHz}$, $t_r = 6\text{ns}$, $t_f = 6\text{ns}$, $t_w = 500\text{ns}$,
 $V_p = 3\text{Vp.p}$, $Z_0 = 50\Omega$
- (2) C_L includes probe and jig capacitance.

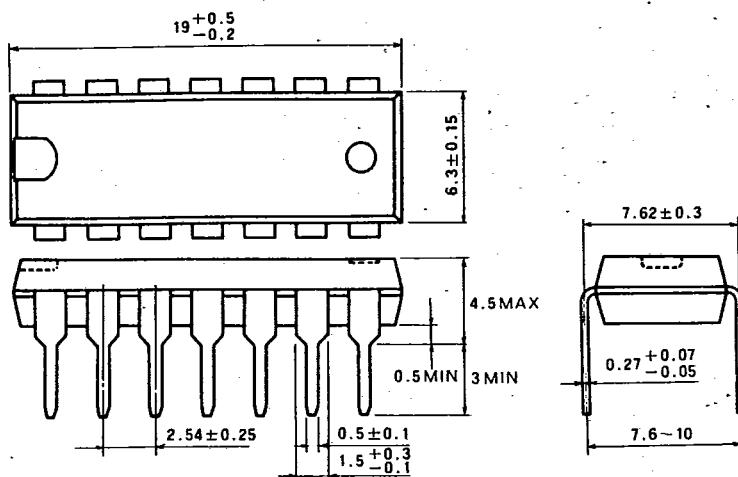
MITSUBISHI LSTTLs
PACKAGE OUTLINES

MITSUBISHI {DGTL LOGIC} 07E D 6249827 0013561 3

T-90-20

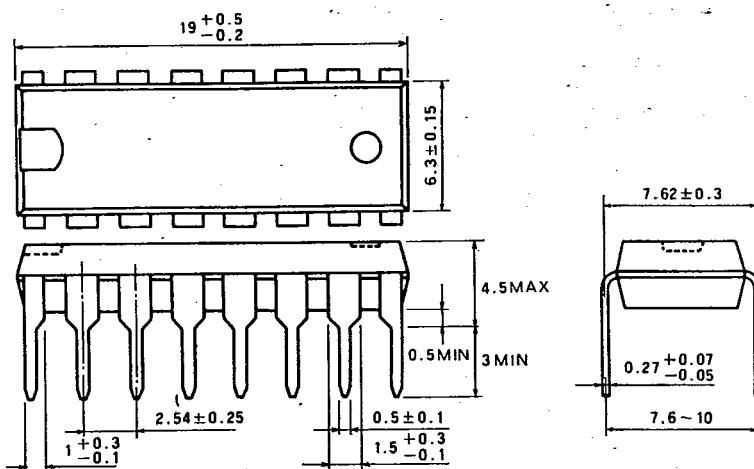
TYPE 14P4 14-PIN MOLDED PLASTIC DIL

Dimension in mm



TYPE 16P4 16-PIN MOLDED PLASTIC DIL

Dimension in mm



TYPE 20P4 20-PIN MOLDED PLASTIC DIL

Dimension in mm

